

# Phase gate of one superconducting qubit simultaneously controlling $n$ qubits in a cavity

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We propose how to realize a three-step controlled-phase gate of one superconducting qubit simultaneously controlling  $n$  qubits selected from  $N$  qubits in a cavity ( $1 < n < N$ ). The operation time of this gate is independent of the number  $n$  of qubits involved in the gate operation. This phase gate controlling at once  $n$  qubits is insensitive to the initial state of the cavity mode and can be used to produce an analogous CNOT gate simultaneously acting on  $n$  qubits.

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*Introduction.*— Quantum information processing has attracted considerable interest during the past decade. The building blocks of quantum computing are single-qubit and two-qubit logic gates. So far, a large number of theoretical proposals for realizing two-qubit gates in many physical systems have been proposed. Moreover, two-qubit controlled-not (CNOT) or controlled-phase (CP) gates have been experimentally demonstrated in, e.g., cavity QED [1], ion traps [2], NMR [3], quantum dots [4], and superconducting qubits [5, 6].

Attention is now shifting to the physical realization of *multi*-qubit controlled gates (e.g., [7]) instead of just *two*-qubit gates. It is known that multi-qubit controlled gates play a significant role in constructing network quantum computation circuits. When using the conventional gate-decomposition protocols to construct a multi-qubit controlled gate [8, 9], the procedure usually becomes complicated (especially for large  $n$ ), as the number of single-qubit and two-qubit gates required for the gate implementation heavily depends on the number  $n$  of qubits. Therefore, building a multi-qubit controlled gate may become very difficult since each elementary gate requires turning on and off a given Hamiltonian for a certain period of time, and each additional basic gate adds experimental complications and the possibility of more errors.

Several methods for constructing phase gates with  $n$ -control qubits acting on one target qubit based on cavity QED or ion traps have been recently proposed [10, 11, 12, 13]. These methods open a new way for realizing quantum controlled-phase gates with multiple control qubits. However, we note that these proposals [10, 11, 12, 13] cannot be extended to perform a different type of significant multi-qubit controlled-phase gate, i.e., quantum controlled-phase gates with one qubit controlling  $n$  target qubits. In this work, we propose how to realize a three-step controlled-phase gate of one superconducting (SC) qubit simultaneously controlling  $n$  qubits selected from  $N$  qubits in a cavity ( $1 < n < N$ ). To achieve this, we construct an effective Hamiltonian which contains interaction terms between the control qubit and

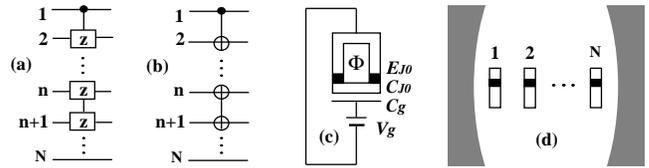


FIG. 1: (a) A controlled-phase (CP) gate simultaneously acting on  $n$  target qubits (2, 3, ...,  $n + 1$ ), i.e.,  $n$  two-qubit CP gates. Here, Z represents a controlled-phase flip on each target qubit. Namely, if the control qubit (i.e., qubit 1) is in the state  $|1\rangle$ , then the state  $|1\rangle$  at each Z is phase-flipped as  $|1\rangle \rightarrow -|1\rangle$ , while the state  $|0\rangle$  remains unchanged. (b) CNOT gate simultaneously controlling  $n$  qubits (2, 3, ...,  $n + 1$ ), obtained from our  $n$ -qubit CP gate. The symbol  $\oplus$  represents a CNOT gate on each target qubit. If the control qubit is in the state  $|1\rangle$ , then the state at  $\oplus$  is bit flipped as  $|1\rangle \rightarrow |0\rangle$  and  $|0\rangle \rightarrow |1\rangle$ . However, when the control qubit is in the state  $|0\rangle$ , the state at  $\oplus$  remains unchanged. (c) Diagram of a superconducting (SC) charge qubit. (d)  $N$  SC qubits are placed in a microwave cavity, from which a subset of qubits, selected for the gate, are coupled to each other via the cavity mode. In (a) and (b), the qubits ( $n + 2, n + 3, \dots, N$ ) are not involved in the gate operation, by setting their  $\Phi = \Phi_0/2$ ,  $V_g^{\text{dc}} = e/C_g$ , and  $V_g^{\text{ac}} = 0$ .

each subordinate or target qubit. We will denote this  $n$ -target-qubits control-phase gate as a NTCP gate (see Fig. 1(a)). As shown below, our proposal has the following advantages: (i) the  $n$  two-qubit controlled-phase gates involved in the NTCP gate can be performed simultaneously; (ii) the operation time required for the gate implementation is independent of the number  $n$  of qubits involved in the gate operation; (iii) this approach is insensitive to the initial state of the cavity mode, and thus no preparation for the initial state of the cavity mode is needed; (iv) no large detuning between the qubits and the cavity mode is required and thus the gate operation can be speeded up; and (v) the proposal is remarkably simple, requiring only three basic operations. Note that a CNOT gate of one qubit simultaneously controlling  $n$  qubits, shown in Fig. 1(b), can also be achieved using

the present proposal. This is because the  $n$ -target-qubits CNOT gate is equivalent to a NTCP gate plus a single-qubit Hadamard gate acting on each target qubit before and after the NTCP gate. To the best of our knowledge, our proposal is the first to demonstrate that a powerful phase gate, *synchronously controlling  $n$  qubits*, can be achieved with superconducting charge qubits in a cavity, which can be initially in an arbitrary state. This proposal is quite general and can be easily extended to other physical systems (such as atomic qubits, quantum dots, and superconducting flux or phase qubits), since the relevant effective Hamiltonian [Eq. (10) below] can be constructed by applying suitable external driving pulses. We believe that this work is of general interest and significance because it provides a simple protocol for performing controlled-phase (or controlled-not) gates with multiple-target-qubits, which are important in quantum information processing such as entanglement preparation [14], error correction [15], quantum algorithms (e.g., the Discrete Cosine Transform [16]), and quantum cloning [17].

*Model.*— The superconducting charge qubit considered here, shown in Fig. 1(c), consists of a small box, connected to a symmetric superconducting quantum interference device (SQUID) with capacitance  $C_{J0}$  and Josephson coupling energy  $E_{J0}$ . In the charge regime  $\Delta \gg E_c \gg E_{J0} \gg k_B T$  (here,  $k_B$ ,  $\Delta$ ,  $E_c$ , and  $T$  are the Boltzmann constant, gap, charging energy, and temperature, respectively), only two charge states,  $n = 0$  and  $n = 1$ , are important for the dynamics of the system, and thus this device [18] behaves as a two-level system  $\{|0\rangle, |1\rangle\}$ . For  $N$  identical charge qubits placed in a single-mode cavity [19, 20] (Fig. 1(d)), one can select a subset of qubits for the gate, while the remaining qubits are not involved in the gate operation, by setting their  $\Phi = \Phi_0/2$ ,  $V_g^{\text{dc}} = e/C_g$ , and  $V_g^{\text{ac}} = 0$  to have them decoupled from the cavity mode and their free Hamiltonian being zero. Here,  $\Phi_0$  is the flux quantum,  $\Phi$  is the external magnetic flux piercing the SQUID loop,  $V_g^{\text{dc}}$  is the dc gate voltage,  $V_g^{\text{ac}}$  is the ac gate voltage, and  $C_g$  is the gate capacitance. The method presented below for a NTCP gate works for a subset of qubits selected from the  $N$  qubits in a cavity, because the qubit-qubit coupling, mediated by the cavity mode, does not depend on the relative position between any two qubits. Without loss of generality, we assume that the set of qubits involved in the gate operation are the  $n + 1$  qubits labelled by 1, 2, ..., and  $n + 1$  (here,  $1 < n < N$ ). The Hamiltonian for the  $n + 1$  qubits and the cavity mode is

$$H = \hbar\omega_c a^\dagger a + E_z (V_g^{\text{dc}}) S_z - E_J(\Phi) S_x + \hbar\Omega \cos(\omega t + \varphi) S_z + \hbar g (a + a^\dagger) S_z, \quad (1)$$

where  $a$  is the photon annihilation operator of the cavity mode with frequency  $\omega_c$ ;  $S_z$  and  $S_x$  are the collective operators of the qubits, given by  $S_z = \sum_{j=1}^{n+1} \sigma_{z,j}$  and  $S_x =$

$\sum_{j=1}^{n+1} \sigma_{x,j}$ , with Pauli operators  $\sigma_{z,j} = |0\rangle_j \langle 0| - |1\rangle_j \langle 1|$  and  $\sigma_{x,j} = |0\rangle_j \langle 1| + |1\rangle_j \langle 0|$  for qubit  $j$ ;  $g$  is the coupling constant between the cavity mode and each qubit; and  $\Omega$  is the Rabi frequency. In addition,  $E_z = -2E_c(1 - 2n_g^{\text{dc}})$  with the charge energy  $E_c = e^2/(2C_g + 4C_{J0})$  and  $n_g^{\text{dc}} = C_g V_g^{\text{dc}}/(2e)$ . The effective Josephson coupling is given by  $E_J(\Phi) = 2E_{J0} \cos(\pi\Phi/\Phi_0)$ . The fourth term of Eq. (1) comes from the ac gate voltage given by  $V_g^{\text{ac}} = V_0 \cos(\omega t + \varphi)$  while the last term arises from the quantum part of the gate voltage given by  $V_g^{\text{qu}} = V_0^{\text{qu}}(a + a^\dagger)$ , which is caused by the electric field of the cavity mode when a qubit is inside the cavity. Finally, the coupling constant  $g$  and the Rabi frequency  $\Omega$  are given by  $g = 2E_c C_g V_0^{\text{qu}}/(\hbar e)$  and  $\Omega = 2E_c C_g V_0/(\hbar e)$ , respectively. Hereafter, we set  $E_z = 0$  (i.e.,  $n_g^{\text{dc}} = 1/2$ ),  $\omega_0 = E_J(\Phi)/\hbar$ , and  $\hbar = 1$ . From the last two terms of Eq. (1), in the interaction picture with respect to  $H_0 = \omega_c a^\dagger a - \omega_0 S_x$ , we obtain (under a rotating-wave approximation and assuming  $\omega = 2\omega_0$ ):

$$H_1 = \frac{\Omega}{2} [S_z \cos \varphi + i(S^+ - S^-) \sin \varphi], \quad (2)$$

$$H_2 = \frac{g}{2} [e^{-i\delta t} a (S_z + S^- - S^+) + \text{H.c.}], \quad (3)$$

where  $S^+$  and  $S^-$  are, respectively, the raising and lowering operators for the qubits, given by  $S^+ = \sum_{j=1}^{n+1} |1\rangle_j \langle 0|$  and  $S^- = \sum_{j=1}^{n+1} |0\rangle_j \langle 1|$ ; and  $\delta = \omega_c - \omega$  is the detuning between the cavity-mode frequency and the frequency of the ac gate voltage.

*Unitary evolution.*— We now consider two special cases:  $\varphi = 0$  and  $\delta < 0$ , as well as  $\varphi = \pi$  and  $\delta > 0$ . The results from the unitary evolution, obtained for these two special cases, will be employed below for the gate implementation. Let us begin with the case  $\varphi = 0$  and  $\delta < 0$ . Performing the transformation  $e^{-iH_1 t}$  on  $H_2$  for  $\varphi = 0$ , and assuming  $\Omega \gg |\delta|$ ,  $g$ , we obtain

$$H_2' = e^{iH_1 t} H_2 e^{-iH_1 t} = \frac{g}{2} (e^{-i\delta t} a + e^{i\delta t} a^\dagger) S_z. \quad (4)$$

The evolution operator  $U'$  for  $H_2'$  takes the form [13, 21, 22]

$$U'(t) = e^{-iA(t)S_z^2} e^{-iB(t)S_z a} e^{-iB^*(t)S_z a^\dagger} \quad (5)$$

with  $B(t) = ig(e^{-i\delta t} - 1)/(2\delta)$  and  $A(t) = g[2B^*(t) - gt]/(4\delta)$ . When  $t = \tau = 2\pi/|\delta|$ , we have  $B(\tau) = 0$  and  $A(\tau) = -g^2\tau/(4\delta)$ . Then, the evolution operator (in the Schrödinger picture) of the qubit system is

$$U(\tau) = e^{-iH_0\tau} e^{-iH_1\tau} U'(\tau) = \exp(i\omega_0\tau S_x) \exp(-i\Omega\tau S_z/2) \exp(-i\lambda\tau S_z^2), \quad (6)$$

where  $\lambda = -g^2/(4\delta) > 0$ . Note that for  $\omega_0\tau = m\pi$  (hereafter  $m$  is an interger), one has  $\exp(i\omega_0\tau S_x) = (-1)^m \prod_{j=1}^{n+1} I_j$ , where  $I_j$  is the identity operator for qubit  $j$ . Thus, the operator  $U$  reduces to

$$U(\tau) = \exp(-i\Omega\tau S_z/2) \exp(-i\lambda\tau S_z^2). \quad (7)$$

Let us now consider the case  $\varphi = \pi$  and  $\delta > 0$ . For convenience, we replace  $\delta$  and  $g$  by  $\delta'$  and  $g'$ , respectively. By setting  $E_z = E_J(\Phi) = \Omega = 0$  for qubit 1, the coupling of qubit 1 with the cavity mode becomes negligibly small. The terms corresponding to  $j = 1$  can thus be dropped off from  $H$ ,  $H_0$ ,  $H_1$ , and  $H_2$ . Note that the reduced Hamiltonian (2) and (3) for  $\varphi = \pi$  have forms similar to those for  $\varphi = 0$ . Therefore, it is straightforward to show that under the condition  $\Omega \gg \delta'$ ,  $g'$ , when  $t = \tau' = 2\pi/\delta'$ , the evolution operator of the qubits becomes

$$\tilde{U}(\tau') = \exp(i\omega_0\tau' S'_x) \exp(i\Omega\tau' S'_z/2) \exp(i\lambda'\tau' S'^2_z), \quad (8)$$

where  $\lambda' = g'^2/(4\delta')$ ,  $S'_z = \sum_{j=2}^{n+1} \sigma_{z,j}$  and  $S'_x = \sum_{j=2}^{n+1} \sigma_{x,j}$ . The operator  $\tilde{U}$  can be reduced to

$$\tilde{U}(\tau') = \exp(i\Omega\tau' S'_z/2) \exp(i\lambda'\tau' S'^2_z) \quad (9)$$

for  $\omega_0\tau' = m\pi$ . Finally, we note that the operator  $U$  (or  $\tilde{U}$ ) does not include the photon operator  $a$  or  $a^+$  of the cavity mode. Hence, the cavity mode can be initially in an arbitrary state (e.g., in a vacuum state, a Fock state, a coherent state, or even a thermal state).

*Implementation of a NTCP gate.*— The operations for the gate implementation and the unitary evolutions after each step of operation are listed below:

Step (i): Set  $V_g^{\text{dc}} = e/C_g$  and  $V_g^{\text{ac}} = V_0 \cos(\omega t)$  for each qubit. Choose  $\Phi$  (applied to each qubit) and  $\omega$  appropriately such that  $\omega_0(\Phi) = \omega/2 = 0.5m\omega_c/(m-1)$ , leading to  $\delta = -\omega_c/(m-1) < 0$  ( $m > 1$ ) and thus  $\omega_0\tau = m\pi$  for  $\tau = -2\pi/\delta$ . One can see that this is the case discussed above for  $\varphi = 0$  and  $\delta < 0$ . Thus, the  $U$  of Eq. (7) is the evolution operator for the qubit system for the time  $\tau = -2\pi/\delta$ .

Step (ii): Set  $V_g^{\text{dc}} = e/C_g$ ,  $V_g^{\text{ac}} = 0$ , and  $\Phi = \Phi_0/2$  for qubit 1; while set  $V_g^{\text{dc}} = e/C_g$  and  $V_g^{\text{ac}} = V_0 \cos(\omega t + \pi)$  for qubits (2, 3, ...,  $n+1$ ). In addition, set  $\omega_0(\Phi) = \omega/2 = 0.5(m-2)\omega_c/(m-1)$  for qubits (2, 3, ...,  $n+1$ ), by choosing  $\Phi$  and  $\omega$  appropriately. Accordingly, we have  $\delta' = |\delta| = \omega_c/(m-1) > 0$  ( $m > 2$ ) and thus  $\omega_0\tau' = (m-2)\pi$  for  $\tau' = 2\pi/\delta'$ . One can see that this is the case discussed above for  $\varphi = \pi$  and  $\delta > 0$ . Hence, for an evolution time  $\tau' = 2\pi/\delta'$ , the evolution operator of the qubit system is  $\tilde{U}$  in Eq. (9).

When  $\delta' = -\delta$  and  $g' = g$ , we have  $\lambda' = \lambda$  and  $\tau' = \tau$ . In this case, the joint time evolution operator, after the above two-step operation, is

$$\begin{aligned} U(2\tau) &= \tilde{U}(\tau)U(\tau) \\ &= \exp(-i\Omega\tau\sigma_{z,1}/2) \exp(-i2\lambda\tau\sigma_{z,1}S'_z). \end{aligned}$$

The condition  $\delta' = -\delta$  is automatically satisfied by the steps above.

Step (iii): Set  $V_g^{\text{ac}} = 0$  and  $\Phi = \Phi_0/2$  for each qubit. Set  $V_g^{\text{dc}} = 2en_{g,1}^{\text{dc}}/C_g$  for qubit 1 while  $V_g^{\text{dc}} = 2en_g^{\text{dc}}/C_g$  for qubits (2, 3, ...,  $n+1$ ). In addition, adjust the cavity-mode frequency [23, 24] such that it is highly detuned

with the  $|0\rangle \leftrightarrow |1\rangle$  transition of each qubit. Thus, the Hamiltonian in Eq. (1) for the qubit system becomes  $H = E_{z,1}\sigma_{z,1} + E_z S'_z$ , where  $E_{z,1} = -2E_c(1 - 2n_{g,1}^{\text{dc}})$  while  $E_z = -2E_c(1 - 2n_g^{\text{dc}})$ . For a time interval  $\tau$ , the corresponding evolution operator is then given by

$$\bar{U}(\tau) = \exp(-iE_{z,1}\tau\sigma_{z,1}/\hbar) \exp(-iE_z\tau S'_z/\hbar).$$

With a choice of  $n_{g,1}^{\text{dc}} = 0.5 - \hbar(4n\lambda + \Omega)/(8E_c)$  and  $n_g^{\text{dc}} = 0.5 - \hbar\lambda/(2E_c)$ , one can find from  $U(2\tau)$  and  $\bar{U}(\tau)$  above that the joint time evolution operator, after the above three-step operation, is given by  $U(3\tau) = \bar{U}(\tau)U(2\tau) = \prod_{j=2}^{n+1} U_p(1, j)$ , with  $U_p(1, j) = \exp[i2\lambda\tau(\sigma_{z,1} + \sigma_{z,j} - \sigma_{z,1}\sigma_{z,j})]$ . For the qubit pair (1,  $j$ ), we have  $U_p(1, j)|r_1\rangle|s_j\rangle = |r_1\rangle|s_j\rangle$  (with  $rs = 00, 01$ , or  $10$ ), while  $U_p(1, j)|1_1\rangle|1_j\rangle = \exp(-i8\lambda\tau)|1_1\rangle|1_j\rangle$ , where an overall phase factor  $\exp(i2\lambda\tau)$  is omitted. This result shows that for  $8\lambda\tau = (2k+1)\pi$ , i.e.,  $|\delta| = 2g/\sqrt{2k+1}$  ( $k$  is an integer), a two-qubit controlled-phase gate described by  $U_p(1, j) = I_{1j} - 2|1_11_j\rangle\langle 1_11_j|$  is achieved for the qubit pair (1,  $j$ ). Here and below, qubit 1 acts as a control while qubit  $j$  as a target, and  $I_{1j}$  is the identity operator for the two qubits 1 and  $j$ . All above conditions on  $\delta$  can be satisfied with an appropriate choice of  $m, k, \omega_c$  and  $g$ .

Finally, we have  $U(3\tau) = \prod_{j=2}^{n+1} (I_{1j} - 2|1_11_j\rangle\langle 1_11_j|)$ , which demonstrates that  $n$  two-qubit controlled-phase gates are simultaneously performed on the qubit pairs (1, 2), (1, 3), ..., and (1,  $n+1$ ), respectively. Note that each qubit pair contains the *same* control qubit (i.e., qubit 1) and a *different* target qubit. Hence, a NTCP gate with  $n$  target qubits (2, 3, ...,  $n+1$ ) and one control qubit (i.e., qubit 1) is obtained after the above three-step operation. A brief overview on this NTCP gate is in Fig. 1(a).

It can be found from  $U(3\tau)$  and  $U_p(1, j)$  above that the present method is based on an effective Hamiltonian

$$H_{\text{eff}} = \sum_{j=2}^{n+1} H_{1j} = -2\lambda \sum_{j=2}^{n+1} (\sigma_{z,1} + \sigma_{z,j} - \sigma_{z,1}\sigma_{z,j}), \quad (10)$$

which contains the interaction terms between the control qubit and each target qubit, but does not include interaction terms between any two target qubits. Note that each term  $H_{1j}$  in Eq. (10) acts on a different target qubit, with the same controlled qubit, and that any two terms  $H_{1j}$  for different  $j$  commute with each other. Therefore, the  $n$  two-qubit controlled-phase gates forming the NTCP gate can be simultaneously performed on the qubit pairs (1, 2), (1, 3), ..., and (1,  $n+1$ ).

*Proposed experiment.*— For this method to work, the following conditions should be met. For steps (i) and (ii), the Rabi frequency  $\Omega$  needs to be much larger than  $g, g', -\delta, \delta'$ ; the deviation from the degeneracy point is given by  $\varepsilon_0 = \hbar(\Omega + g)/(4E_c)$ , which needs to be a small number to have the qubits working near the degeneracy point. For step (iii), from  $n_{g,1}^{\text{dc}}$  and  $n_g^{\text{dc}}$  above, we

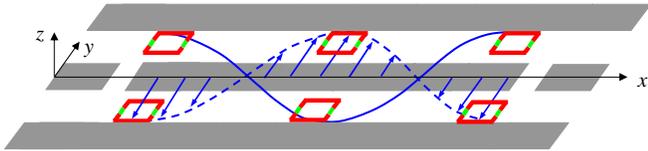


FIG. 2: (Color online) Proposed setup for six charge qubits (red squares) and a (grey) standing-wave quasi-one dimensional coplanar waveguide cavity. Each qubit is placed at an antinode of the electric field. The two blue curves represent the standing-wave electric field, along the  $y$ -direction.

obtain  $\varepsilon_1 = \hbar(4n\lambda + \Omega)/(8E_c)$  and  $\varepsilon_2 = \hbar\lambda/(2E_c)$ . Here,  $\varepsilon_1$  is the deviation from the degeneracy point for the control qubit 1 while  $\varepsilon_2$  for the  $n$  target qubits, which should be sufficiently small to ensure that the qubits work near their degeneracy points.

As a concrete example, let us consider the experimental feasibility of implementing a five-target-qubit controlled-phase gate using superconducting charge qubits with  $C_g = 1$  aF,  $C_{J_0} = 300$  aF,  $E_c/h = 32$  GHz,  $E_{J_0}/h = 5$  GHz,  $T_2 = 500$  ns, and  $T_1 = 7.3$   $\mu$ s. The charge qubits with these parameters are available at present [25, 26]. For a superconducting 1D standing-wave coplanar waveguide cavity and each qubit placed at an antinode of the cavity field (as shown in Fig.2), the amplitude of the quantum part of the gate voltage is given by [20]  $V_0^{\text{qu}} = (\hbar\omega_c)^{1/2} (Lc_0)^{-1/2}$ , where  $L$  is the cavity length and  $c_0$  is the capacitance per unit length of the cavity. The coupling constant is then given by  $g = 2E_c C_g (\hbar e)^{-1} (\hbar\omega_c)^{1/2} (Lc_0)^{-1/2}$ , showing that  $g$  does not depend on the detuning  $\delta$ . Therefore, the condition  $g = g'$  required above can be satisfied. For charge qubits with the above parameters and a cavity with  $\omega_c/(2\pi) = 10$  GHz,  $L = \lambda \sim 12$  mm,  $c_0 \sim 0.22$  aF/ $\mu$ m, and  $\varepsilon_e = 6.3$ , a simple calculation gives  $g/2\pi \sim 100$  MHz, which is experimentally available [26]. Here,  $\lambda$  is the wavelength of the cavity mode and  $\varepsilon_e$  is the effective relative dielectric constant. With the choice of  $|\delta| \sim 0.9g$  (corresponding to the integers  $m = 112$ ,  $k = 2$ ), the total operation time  $t_{\text{op}} = 3\tau$  would be  $\sim 33$  ns, which is much shorter than the dephasing time  $T_2$  and the cavity-mode lifetime  $\kappa^{-1} = Q/\omega_c \sim 159$  ns for a cavity with  $Q = 10^4$ . Here,  $Q$  is the (loaded) quality factor of the cavity. Note that a quality factor  $Q = 10^4$  has been demonstrated by cavity QED experiments with superconducting charge qubits [27]. For a qubit-cavity system with the parameters given above, we have  $\varepsilon_0 \sim 5.46 \times 10^{-3}$ ,  $\varepsilon_1 \sim 4.51 \times 10^{-3}$ , and  $\varepsilon_2 \sim 4.34 \times 10^{-4}$  for  $\Omega/(2\pi) \sim 600$  MHz. Therefore, the conditions for the qubits to work near the degeneracy point are well satisfied.

Note also that the adjustment of the cavity-mode frequency is unnecessary because one can adjust the dc gate voltage to have the qubits decoupled from the cavity mode. However, when a large number of qubits are involved, it is much more convenient to adjust the cavity mode frequency rather than adjusting the dc gate voltage of each qubit. This is because all qubits can be simultaneously decoupled from the cavity mode by adjusting the cavity mode frequency, but one will need to individually adjust step-by-step the dc gate voltage for each qubit to decouple the qubits from the cavity mode.

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- [1] Q.A. Turchette *et al.*, Phys. Rev. Lett. **75**, 4710 (1995).  
A. Rauschenbeutel *et al.*, *ibid.* **83**, 5166 (1999).
  - [2] C. Monroe *et al.*, Phys. Rev. Lett. **75**, 4714 (1995).
  - [3] J.A. Jones *et al.*, Nature (London) **393**, 344 (1998).
  - [4] X. Li *et al.*, Science **301**, 809 (2003).
  - [5] T. Yamamoto *et al.*, Nature (London) **425**, 941 (2003).
  - [6] P.C. de Groot *et al.*, Nature (London) **447**, 836 (2007).
  - [7] T. Monz *et al.*, Phys. Rev. Lett. **102**, 040501 (2009).
  - [8] A. Barenco *et al.*, Phys. Rev. A **52**, 3457 (1995).
  - [9] M. Möttönen *et al.*, Phys. Rev. Lett. **93**, 130502 (2004).
  - [10] C.P. Yang and S. Han, Phys. Rev. A **72**, 032311 (2005).
  - [11] L.M. Duan *et al.*, Phys. Rev. A **72**, 032333 (2005).
  - [12] X.M. Lin *et al.*, Phys. Rev. A **73**, 012323 (2006).
  - [13] X. Wang *et al.*, Phys. Rev. Lett. **86**, 3907 (2001).
  - [14] M. Šašura *et al.*, Phys. Rev. A **64**, 012305 (2001).
  - [15] M. A. Nielsen and I. L. Chuang, *Quantum Computation and Quantum Information* (Cambridge University Press, Cambridge, England, 2001).
  - [16] T. Beth and M. Rötteler, *Quantum Information*, Vol. 173, Ch. 4, p. 96 (Springer, Berlin, 2001).
  - [17] S. L. Braunstein *et al.*, Phys. Rev. A **63**, 052313 (2001).
  - [18] Y. Makhlin *et al.*, Rev. Mod. Phys. **73**, 357 (2001); J.Q. You *et al.*, Phys. Today **58** (11), 42 (2005); J. Clarke and F. K. Wilhelm, Nature **453**, 1031 (2008).
  - [19] J.Q. You *et al.*, Phys. Rev. B **68**, 064509 (2003); J.Q. You *et al.*, *ibid.* **68**, 024510 (2003).
  - [20] A. Blais *et al.*, Phys. Rev. A **69**, 062320 (2004).
  - [21] A. Sørensen *et al.*, Phys. Rev. A **62**, 022311 (2000).
  - [22] Y.D. Wang *et al.*, Phys. Rev. B **70**, 224515 (2004).
  - [23] M. Sandberg *et al.*, Appl. Phys. Lett. **92**, 203501 (2008).
  - [24] A. Palacios-Laloy *et al.*, J. Low Temp. Phys. **151**, 1034 (2008).
  - [25] O. Astafiev *et al.*, Phys. Rev. Lett. **93**, 267007 (2004).
  - [26] A. Blais *et al.*, Phys. Rev. A **75**, 032329 (2007).
  - [27] A. Wallraff *et al.*, Nature (London) **431**, 162 (2004).